

## 256-Position One-Time Programmable Dual-Channel I<sup>2</sup>C Digital Potentiometers

## AD5172/AD5173

#### **FEATURES**

2-channel, 256-position OTP (one-time programmable) set-and-forget resistance setting, low cost alternative to EEMEM Unlimited adjustments prior to OTP activation OTP overwrite allows dynamic adjustments with user defined preset End-to-end resistance: 2.5 k $\Omega$ , 10 k $\Omega$ , 50 k $\Omega$ , 100 k $\Omega$ Compact MSOP-10 (3 mm × 4.9 mm) package Fast settling time:  $t_s = 5 \mu s$  typ in power-up Full read/write of wiper register Power-on preset to midscale Extra package address decode pins AD0 and AD1 (AD5173) Single supply 2.7 V to 5.5 V Low temperature coefficient: 35 ppm/°C Low power,  $I_{DD} = 6 \mu A \max$ Wide operating temperature: -40°C to +125°C Evaluation board and software are available Software replaces µC in factory programming applications

#### APPLICATIONS

Systems calibration Electronics level setting Mechanical Trimmers® replacement in new designs Permanent factory PCB setting Transducer adjustment of pressure, temperature, position, chemical, and optical sensors RF amplifier biasing Automotive electronics adjustment Gain control and offset adjustment

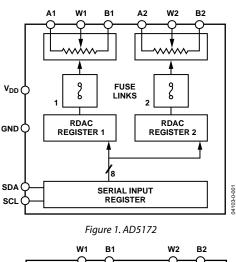
#### **GENERAL OVERVIEW**

The AD5172/AD5173 are dual channel, 256-position, one-time programmable (OTP) digital potentiometers<sup>1</sup> that employ fuse link technology to achieve memory retention of resistance setting. OTP is a cost-effective alternative to EEMEM for users who do not need to program the digital potentiometer setting in memory more than once. This device performs the same electronic adjustment function as mechanical potentiometers or variable resistors with enhanced resolution, solid-state reliability, and superior low temperature coefficient performance.

The AD5172/AD5173 are programmed using a 2-wire, I<sup>2</sup>C compatible digital interface. Unlimited adjustments are allowed before permanently setting the resistance value. During OTP activation, a permanent blow fuse command freezes the wiper position (analogous to placing epoxy on a mechanical trimmer).

#### Rev. A

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FUNCTIONAL BLOCK DIAGRAMS

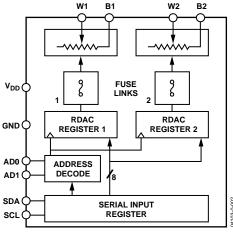


Figure 2. AD5173

Unlike traditional OTP digital potentiometers, the AD5172/ AD5173 have a unique temporary OTP overwrite feature that allows for new adjustments even after the fuse has been blown. However, the OTP setting is restored during subsequent powerup conditions. This feature allows users to treat these digital potentiometers as volatile potentiometers with a programmable preset.

For applications that program the AD5172/AD5173 at the factory, Analog Devices offers device programming software running on Windows<sup>®</sup> NT<sup>®</sup>, 2000, and XP<sup>®</sup> operating systems. This software effectively replaces any external I<sup>2</sup>C controllers, thus enhancing the time-to-market of the user's systems.

<sup>1</sup>The terms digital potentiometer, VR, and RDAC are used interchangeably.

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#### **REVISION HISTORY**

Revision A

11/03—Data Sheet Changed from Rev. 0 to Rev. A

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## **ELECTRICAL CHARACTERISTICS**—2.5 kΩ

Table 1.  $V_{DD} = 5 V \pm 10\%$  or  $3 V \pm 10\%$ ;  $V_A = +V_{DD}$ ;  $V_B = 0 V$ ;  $-40^{\circ}C < T_A < +125^{\circ}C$ ; unless otherwise noted

Parameter	Symbol	Conditions	Min	Typ1	Max	Unit
DC CHARACTERISTICS—RHEOSTAT MOD	Ε					
Resistor Differential Nonlinearity <sup>2</sup>	R-DNL	R <sub>WB</sub> , V <sub>A</sub> = No Connect	-2	±0.1	+2	LSB
Resistor Integral Nonlinearity <sup>2</sup>	R-INL	R <sub>WB</sub> , V <sub>A</sub> = No Connect	-6	±0.75	+6	LSB
Nominal Resistor Tolerance <sup>3</sup>	$\Delta R_{AB}$	$T_A = 25^{\circ}C$	-20		+55	%
Resistance Temperature Coefficient	$(\Delta R_{AB}/R_{AB})/\Delta T$	$V_{AB} = V_{DD}$ , Wiper = No Connect		35		ppm/°C
RWB (Wiper Resistance)	RwB	$Code = 0x00, V_{DD} = 5 V$		160	200	Ω
DC CHARACTERISTICS—POTENTIOMETE	R DIVIDER MODE (S	Specifications Apply to all VRs)				
Differential Nonlinearity <sup>4</sup>	DNL		-1.5	±0.1	+1.5	LSB
Integral Nonlinearity <sup>4</sup>	INL		-2	±0.6	+2	LSB
Voltage Divider Temperature Coefficient	$(\Delta V_w/V_w)/\Delta T$	Code = 0x80		15		ppm/°C
Full-Scale Error	Vwfse	Code = 0xFF	-10	-2.5	0	LSB
Zero-Scale Error	Vwzse	Code = 0x00	0	2	10	LSB
RESISTOR TERMINALS						
Voltage Range⁵	$V_A$ , $V_B$ , $V_W$		GND		$V_{\text{DD}}$	V
Capacitance <sup>6</sup> A, B	С <sub>А</sub> , С <sub>В</sub>	f = 1 MHz, Measured to GND, Code = 0x80		45		pF
Capacitance W	Cw	f = 1 MHz, Measured to GND, Code = 0x80		60		pF
Shutdown Supply Current <sup>7</sup>	I <sub>A_SD</sub>	$V_{DD} = 5.5 V$		0.01	1	μA
Common-Mode Leakage	Ісм	$V_A = V_B = V_{DD}/2$		1		nA
DIGITAL INPUTS AND OUTPUTS						
Input Logic High	VIH	$V_{DD} = 5 V$	2.4			V
Input Logic Low	VIL	$V_{DD} = 5 V$			0.8	V
Input Logic High	VIH	$V_{DD} = 3 V$	2.1			V
Input Logic Low	VIL	$V_{DD} = 3 V$			0.6	V
Input Current	lı.	$V_{IN} = 0 V \text{ or } 5 V$			±1	μΑ
Input Capacitance <sup>6</sup>	CIL			5		pF
POWER SUPPLIES						
Power Supply Range	VDD RANGE		2.7		5.5	V
OTP Supply Voltage	V <sub>DD_OTP</sub>	$T_A = 25^{\circ}C$	6		6.5	V
Supply Current	I <sub>DD</sub>	$V_{IH} = 5 V \text{ or } V_{IL} = 0 V$		3.5	6	μΑ
OTP Supply Current	IDD_OTP	$V_{DD_OTP} = 6 V, T_A = 25^{\circ}C$	100			mA
Power Dissipation <sup>8</sup>	P <sub>DISS</sub>	$V_{IH} = 5 \text{ V or } V_{IL} = 0 \text{ V}, V_{DD} = 5 \text{ V}$			30	μW
Power Supply Sensitivity	PSS	$V_{DD} = 5 V \pm 10\%$ , Code = Midscale		±0.02	±0.08	%/%
DYNAMIC CHARACTERISTICS9						
Bandwidth –3 dB	BW_2.5K	Code = 0x80		4.8		MHz
Total Harmonic Distortion	THDw	$V_{A} = 1 V rms$ , $V_{B} = 0 V$ , $f = 1 kHz$		0.1		%
V <sub>w</sub> Settling Time	ts	$V_A = 5 V$ , $V_B = 0 V$ , $\pm 1 LSB$ Error Band		1		μs
Resistor Noise Voltage Density	en_wb	$R_{WB} = 1.25 \text{ k}\Omega, R_{S} = 0$		3.2		nV/√Hz

<sup>1</sup> Typical specifications represent average readings at 25°C and  $V_{DD} = 5$  V.

<sup>6</sup> Guaranteed by design and not subject to production test.

 $^{9}$  All dynamic characteristics use V<sub>DD</sub> = 5 V.

<sup>&</sup>lt;sup>2</sup> Resistor position nonlinearity error, R-INL, is the deviation from an ideal value measured between the maximum resistance and the minimum resistance wiper positions. R-DNL measures the relative step change from ideal between successive tap positions. Parts are guaranteed monotonic.

<sup>&</sup>lt;sup>3</sup>  $V_{AB} = V_{DD}$ , Wiper ( $V_W$ ) = no connect. <sup>4</sup> INL and DNL are measured at VW with the RDAC configured as a potentiometer divider similar to a voltage output D/A converter.  $V_A = V_{DD}$  and  $V_B = 0$  V. DNL specification limits of  $\pm 1$  LSB maximum are guaranteed monotonic operating conditions.

<sup>&</sup>lt;sup>5</sup> Resistor terminals A, B, W have no limitations on polarity with respect to each other.

<sup>&</sup>lt;sup>7</sup> Measured at the A terminal. The A terminal is open circuited in shutdown mode.

 $<sup>^8</sup>$  P\_{DISS} is calculated from (I\_{DD} \times V\_{DD}). CMOS logic level inputs result in minimum power dissipation.

## ELECTRICAL CHARACTERISTICS—10 k $\Omega$ , 50 k $\Omega$ , 100 k $\Omega$ VERSIONS

Table 2.  $V_{DD} = 5 V \pm 10\%$  or  $3 V \pm 10\%$ ;  $V_A = V_{DD}$ ;  $V_B = 0 V$ ;  $-40^{\circ}C < T_A < +125^{\circ}C$ ; unless otherwise noted

Parameter	Symbol	Conditions	Min	Typ <sup>1</sup>	Max	Unit
DC CHARACTERISTICS—RHEOSTAT MODE						
Resistor Differential Nonlinearity <sup>2</sup>	R-DNL	$R_{WB}$ , $V_A = No$ Connect	-1	±0.1	+1	LSB
Resistor Integral Nonlinearity <sup>2</sup>	R-INL	$R_{WB}$ , $V_A = No$ Connect	-2.5	±0.25	+2.5	LSB
Nominal Resistor Tolerance <sup>3</sup>	$\Delta R_{AB}$	$T_A = 25^{\circ}C$	-20		+20	%
Resistance Temperature Coefficient	$(\Delta R_{AB}/R_{AB})/\Delta T$	$V_{AB} = V_{DD}$ , Wiper = No Connect		35		ppm/°C
R <sub>WB</sub> (Wiper Resistance)	R <sub>WB</sub>	$Code = 0x00, V_{DD} = 5 V$		160	200	Ω
DC CHARACTERISTICS—POTENTIOMETER DIV	IDER MODE (Spec	ifications Apply to all VRs)				
Differential Nonlinearity <sup>4</sup>	DNL		-1	±0.1	+1	LSB
Integral Nonlinearity <sup>4</sup>	INL		-1	±0.3	+1	LSB
Voltage Divider Temperature Coefficient	(ΔV <sub>w</sub> /V <sub>w</sub> )/ΔT	Code = 0x80		15		ppm/°C
Full-Scale Error	V <sub>WFSE</sub>	Code = 0xFF	-2.5	-1	0	LSB
Zero-Scale Error	V <sub>WZSE</sub>	Code = 0x00	0	1	2.5	LSB
RESISTOR TERMINALS						
Voltage Range⁵	VA, VB, VW		GND		V <sub>DD</sub>	V
Capacitance <sup>6</sup> A, B	C <sub>A</sub> , C <sub>B</sub>	f = 1 MHz, Measured to GND, Code = 0x80		45		pF
Capacitance <sup>6</sup> W	Cw	f = 1 MHz, Measured to GND, Code = 0x80		60		pF
Shutdown Supply Current <sup>7</sup>	I <sub>A_SD</sub>	$V_{DD} = 5.5 V$		0.01	1	μA
Common-Mode Leakage	Ісм	$V_A = V_B = V_{DD}/2$		1		nA
DIGITAL INPUTS AND OUTPUTS						
Input Logic High	VIH	$V_{DD} = 5 V$	2.4			v
Input Logic Low	VIL	$V_{DD} = 5 V$			0.8	V
Input Logic High	VIH	$V_{DD} = 3 V$	2.1			V
Input Logic Low	VIL	$V_{DD} = 3 V$			0.6	V
Input Current	lı∟	$V_{IN} = 0 V \text{ or } 5 V$			±1	μA
Input Capacitance <sup>6</sup>	CIL			5		pF
POWER SUPPLIES						
Power Supply Range	V <sub>DD RANGE</sub>		2.7		5.5	V
OTP Supply Voltage <sup>8</sup>	V <sub>DD_OTP</sub>		6		6.5	V
Supply Current	I <sub>DD</sub>	$V_{IH} = 5 \text{ V or } V_{IL} = 0 \text{ V}$		3.5	6	μA
OTP Supply Current <sup>9</sup>	I <sub>DD_OTP</sub>		100			mA
Power Dissipation <sup>10</sup>	P <sub>DISS</sub>	$V_{IH} = 5 V \text{ or } V_{IL} = 0 V, V_{DD} = 5 V$			30	μW
Power Supply Sensitivity	PSS	$V_{DD} = +5 V \pm 10\%$ , Code = Midscale		±0.02	±0.08	%/%
DYNAMIC CHARACTERISTICS <sup>11</sup>						
Bandwidth –3 dB	BW	$R_{AB} = 10 \text{ k}\Omega$ , Code = 0x80		600		kHz
		$R_{AB} = 50 \text{ k}\Omega$ , Code = 0x80		100		kHz
		$R_{AB} = 100 \text{ k}\Omega$ , Code = 0x80		40		kHz
Total Harmonic Distortion	THDw	$V_A = 1 \text{ V rms}, V_B = 0 \text{ V}, f = 1 \text{ kHz}, R_{AB} = 10 \text{ k}\Omega$		0.1		%
V <sub>w</sub> Settling Time (10 kΩ/50 kΩ/100 kΩ)	ts	$V_A = 5 V$ , $V_B = 0 V$ , $\pm 1 LSB$ Error Band		2		μs
Resistor Noise Voltage Density	e <sub>N_WB</sub>		9		nV/√Hz	

<sup>&</sup>lt;sup>1</sup> Typical specifications represent average readings at 25°C and  $V_{DD} = 5$  V.

<sup>11</sup> All dynamic characteristics use  $V_{DD} = 5 V$ .

<sup>&</sup>lt;sup>2</sup> Resistor position nonlinearity error, R-INL, is the deviation from an ideal value measured between the maximum resistance and the minimum resistance wiper positions. R-DNL measures the relative step change from ideal between successive tap positions. Parts are guaranteed monotonic.

 $<sup>{}^{3}</sup>V_{AB} = V_{DD}$ , Wiper (V<sub>W</sub>) = no connect.

<sup>&</sup>lt;sup>4</sup> INL and DNL are measured at  $V_W$  with the RDAC configured as a potentiometer divider similar to a voltage output D/A converter.  $V_A = V_{DD}$  and  $V_B = 0$  V.

DNL specification limits of  $\pm 1$  LSB maximum are guaranteed monotonic operating conditions.

<sup>&</sup>lt;sup>5</sup> Resistor terminals A, B, W have no limitations on polarity with respect to each other.

<sup>&</sup>lt;sup>6</sup> Guaranteed by design and not subject to production test.

<sup>&</sup>lt;sup>7</sup> Measured at the A terminal. The A terminal is open circuited in shutdown mode.

<sup>&</sup>lt;sup>8</sup> Different from operating power supply, power supply OTP is used one time only.

<sup>&</sup>lt;sup>9</sup> Different from operating current, supply current for OTP lasts approximately 400 ms for one time only.

 $<sup>^{10}</sup>$  P\_{DISS} is calculated from (I\_{DD}  $\times$  V\_{DD}). CMOS logic level inputs result in minimum power dissipation.

# TIMING CHARACTERISTICS—2.5 k $\Omega$ , 10 k $\Omega$ , 50 k $\Omega$ , 100 k $\Omega$ VERSIONS Table 3. $V_{DD} = 5 V \pm 10\%$ or $3V \pm 10\%$ ; $V_A = V_{DD}$ ; $V_B = 0 V$ ; $-40^{\circ}C < T_A < +125^{\circ}C$ ; unless otherwise noted

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
I <sup>2</sup> C INTERFACE TIMING CHARACTERISTICS <sup>1</sup> (Specifica	tions Apply t	o All Parts)				
SCL Clock Frequency	<b>f</b> <sub>SCL</sub>				400	kHz
t <sub>BUF</sub> Bus Free Time between STOP and START	t1		1.3			μs
t <sub>HD;STA</sub> Hold Time (Repeated START)	t <sub>2</sub>	After this period, the first clock pulse is generated.	0.6			μs
t <sub>LOW</sub> Low Period of SCL Clock	t <sub>3</sub>		1.3			μs
tHIGH High Period of SCL Clock	t4		0.6			μs
t <sub>SU;STA</sub> Setup Time for Repeated START Condition	t₅		0.6			μs
t <sub>HD;DAT</sub> Data Hold Time <sup>2</sup>	t <sub>6</sub>				0.9	μs
t <sub>su;DAT</sub> Data Setup Time	t <sub>7</sub>		100			ns
t <sub>F</sub> Fall Time of Both SDA and SCL Signals	t <sub>8</sub>				300	ns
t <sub>R</sub> Rise Time of Both SDA and SCL Signals	t9				300	ns
tsu;sto Setup Time for STOP Condition	<b>t</b> 10		0.6			μs

<sup>1</sup> See timing diagrams for locations of measured values.

 $^{2}$  The maximum t<sub>HD;DAT</sub> has only to be met if the device does not stretch the LOW period (t<sub>LOW</sub>) of the SCL signal.

#### **ABSOLUTE MAXIMUM RATINGS**

Table 4.  $T_A = 25^{\circ}$ C, unless otherwise noted

Parameter	Value
V <sub>DD</sub> to GND	–0.3 V to +7 V
V <sub>A</sub> , V <sub>B</sub> , V <sub>W</sub> to GND	V <sub>DD</sub>
Terminal Current, Ax–Bx, Ax–Wx, Bx–Wx <sup>1</sup>	
Pulsed	±20 mA
Continuous	±5 mA
Digital Inputs and Output Voltage to GND	0 V to 7 V
Operating Temperature Range	–40°C to +125°C
Maximum Junction Temperature (T <sub>JMAX</sub> )	150°C
Storage Temperature	–65°C to +150°C
Lead Temperature (Soldering, 10 sec)	300°C
Thermal Resistance <sup>2</sup> θ <sub>JA</sub> : MSOP-10	230°C/W

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

<sup>1</sup> Maximum terminal current is bound by the maximum current handling of the switches, maximum power dissipation of the package, and maximum applied voltage across any two of the A, B, and W terminals at a given resistance.

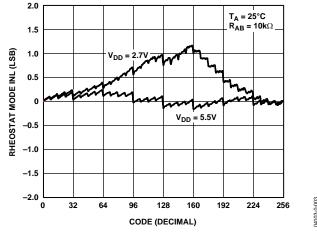
<sup>2</sup> Package power dissipation =  $(T_{JMAX} - T_A)/\theta_{JA}$ .

#### **ESD CAUTION**

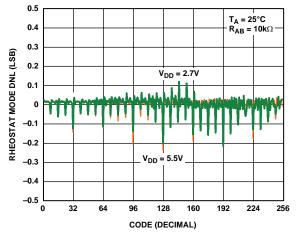
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

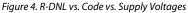


#### **TYPICAL PERFORMANCE CHARACTERISTICS**









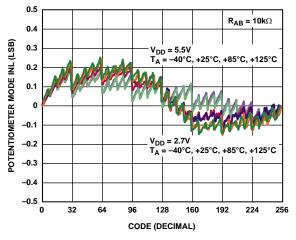
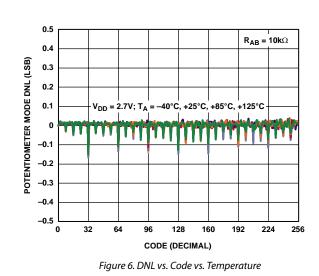
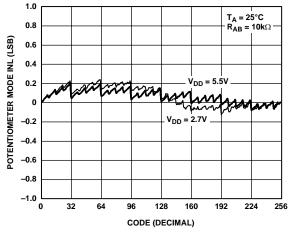
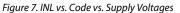


Figure 5. INL vs. Code vs. Temperature







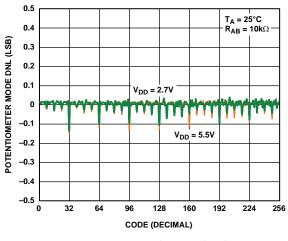
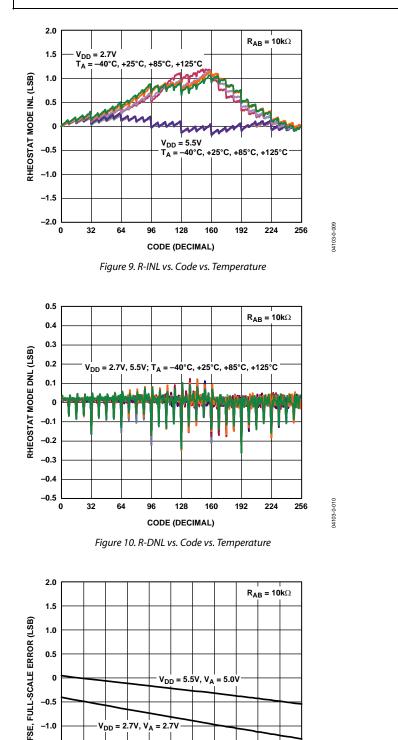


Figure 8. DNL vs. Code vs. Supply Voltages

04103-0-006

04103-0-004

04103-0-005



V<sub>DD</sub> = 2.7V, V<sub>A</sub> = 2.7V

TEMPERATURE (°C)

Figure 11. Full-Scale Error vs. Temperature

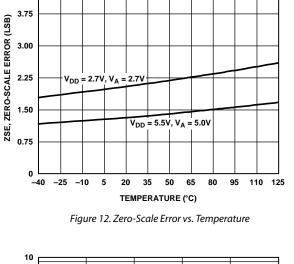
-1.0

-1.5 -2.0

-40

-25

-10 5 20 35 50 65 80 95



 $R_{AB} = 10k\Omega$ 

4.50

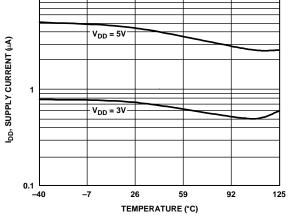


Figure 13. Supply Current vs. Temperature

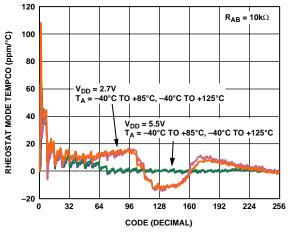


Figure 14. Rheostat Mode Tempco  $\Delta R_{WB}/\Delta T$  vs. Code

04103-0-013

04103-0-012

04103-0-014

04103-0-011

110 125

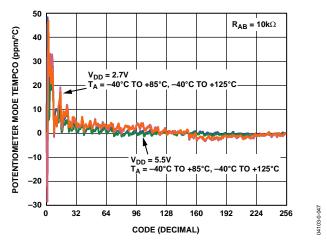


Figure 15. AD5172 Potentiometer Mode Tempco  $\Delta V_{\text{WB}} / \Delta T$  vs. Code

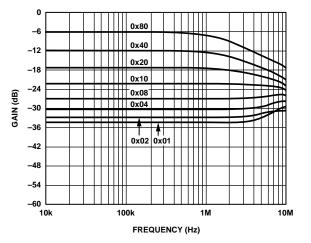


Figure 16. Gain vs. Frequency vs. Code,  $R_{AB} = 2.5 \text{ k}\Omega$ 

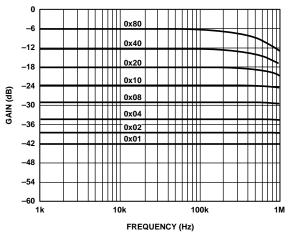


Figure 17. Gain vs. Frequency vs. Code,  $R_{AB} = 10 \text{ k}\Omega$ 

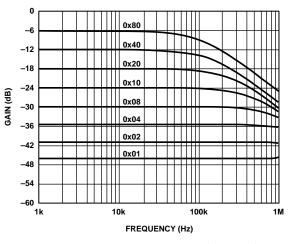
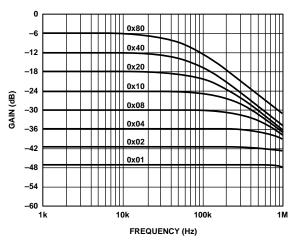


Figure 18. Gain vs. Frequency vs. Code,  $R_{AB} = 50 \text{ k}\Omega$ 





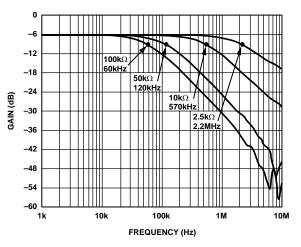
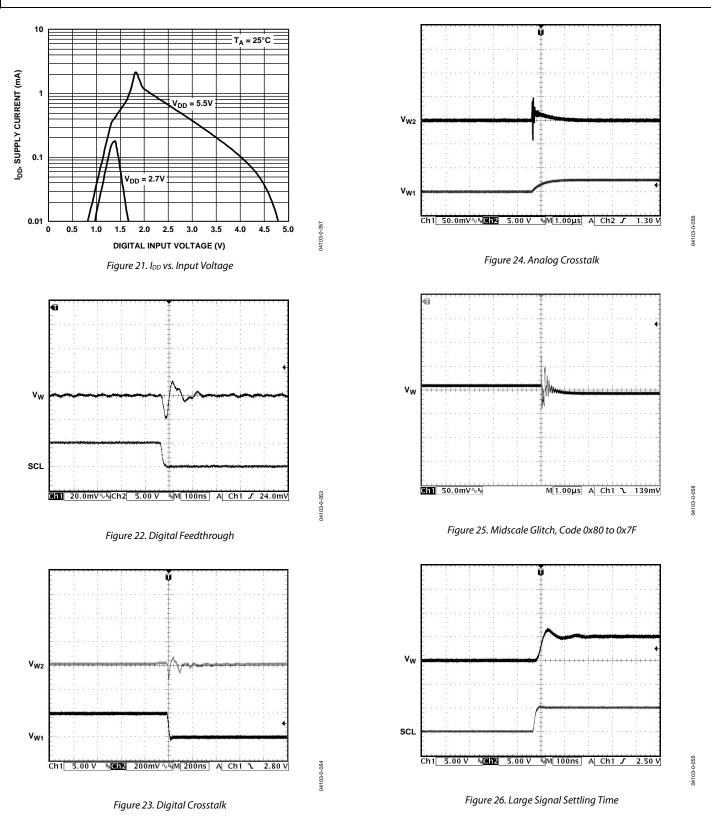


Figure 20. -3 dB Bandwidth @ Code = 0x80

04103-0-050

04103-0-048

04103-0-049



#### **TEST CIRCUITS**

Figure 27 to Figure 34 illustrate the test circuits that define the test conditions used in the product specification tables.

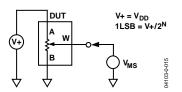


Figure 27. Test Circuit for Potentiometer Divider Nonlinearity Error (INL, DNL)

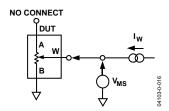


Figure 28. Test Circuit for Resistor Position Nonlinearity Error (Rheostat Operation; R-INL, R-DNL)

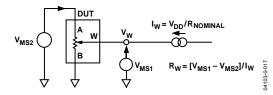


Figure 29. Test Circuit for Wiper Resistance

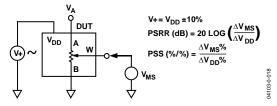


Figure 30. Test Circuit for Power Supply Sensitivity (PSS, PSSR)

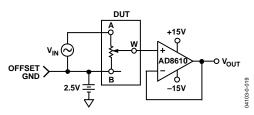


Figure 31. Test Circuit for Gain vs. Frequency

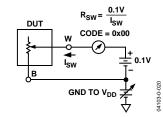


Figure 32. Test Circuit for Incremental On Resistance

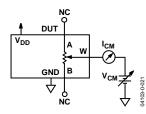


Figure 33. Test Circuit for Common-Mode Leakage Current

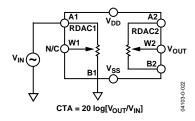


Figure 34. Test Circuit for Analog Crosstalk

## **OPERATION**

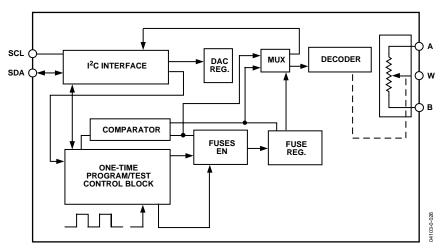


Figure 35. Detailed Functional Block Diagram

The AD5172/AD5173 is a 256-position, digitally controlled variable resistor (VR) that employs fuse link technology to achieve memory retention of resistance setting.

An internal power-on preset places the wiper at midscale during power-on. If the OTP function has been activated, the device powers up at the user-defined permanent setting.

#### **ONE-TIME PROGRAMMING (OTP)**

Prior to OTP activation, the AD5172/AD5173 presets to midscale during initial power-on. After the wiper is set at the desired position, the resistance can be permanently set by programming the T bit high along with the proper coding (see Table 5 and Table 6). Note that fuse link technology requires 6 V to blow the internal fuses to achieve a given setting. The user is allowed only one attempt at blowing the fuses. Once programming is completed, the power supply voltage must be reduced to the normal operating range of 2.7 V to 5.5 V.

The device control circuit has two validation bits, E1 and E0, that can be read back to check the programming status (see Table 7). Users should always read back the validation bits to ensure that the fuses are properly blown. After the fuses have been blown, all fuse latches are enabled upon subsequent power-on; therefore, the output corresponds to the stored setting. Figure 35 shows a detailed functional block diagram.

# PROGRAMMING THE VARIABLE RESISTOR AND VOLTAGE Rheostat Operation

# The nominal resistance of the RDAC between terminals A and B is available in 2.5 k $\Omega$ , 10 k $\Omega$ , 50 k $\Omega$ , and 100 k $\Omega$ . The nominal resistance (R<sub>AB</sub>) of the VR has 256 contact points accessed by the wiper terminal, plus the B terminal contact. The 8-bit data in the RDAC latch is decoded to select one of the 256 possible settings.

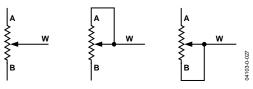


Figure 36. Rheostat Mode Configuration

Assuming a 10 k $\Omega$  part is used, the wiper's first connection starts at the B terminal for data 0x00. Because there is a 50  $\Omega$ wiper contact resistance, such a connection yields a minimum of 100  $\Omega$  (2 × 50  $\Omega$ ) resistance between terminals W and B. The second connection is the first tap point, which corresponds to 139  $\Omega$  (R<sub>WB</sub> = R<sub>AB</sub>/256 + 2 × R<sub>W</sub> = 39  $\Omega$  + 2 × 50  $\Omega$ ) for data 0x01. The third connection is the next tap point, representing 178  $\Omega$  (2 × 39  $\Omega$  + 2 × 50  $\Omega$ ) for data 0x02, and so on. Each LSB data value increase moves the wiper up the resistor ladder until the last tap point is reached at 10,100  $\Omega$  (R<sub>AB</sub> + 2 × R<sub>W</sub>).

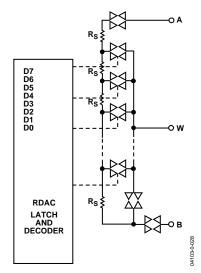


Figure 37. AD5172/AD5173 Equivalent RDAC Circuit

The general equation that determines the digitally programmed output resistance between W and B is

$$R_{WB}(D) = \frac{D}{128} \times R_{AB} + 2 \times R_W \tag{1}$$

where *D* is the decimal equivalent of the binary code loaded in the 8-bit RDAC register,  $R_{AB}$  is the end-to-end resistance, and  $R_W$  is the wiper resistance contributed by the on resistance of the internal switch.

In summary, if  $R_{AB} = 10 \text{ k}\Omega$  and the A terminal is opencircuited, the output resistance  $R_{WB}$  is set for the RDAC latch codes, as shown in Table 5.

Table 5. Codes and Corresponding RWB Resistance

D (Dec.)	R <sub>w</sub> (Ω)	Output State
255	9,961	Full-Scale ( $R_{AB} - 1 LSB + R_W$ )
128	5,060	Midscale
1	139	1 LSB
0	100	Zero-Scale (Wiper Contact Resistance)

Note that in the zero-scale condition, a finite wiper resistance of 100  $\Omega$  is present. Care should be taken to limit the current flow between W and B in this state to a maximum pulse current of no more than 20 mA. Otherwise, degradation or possible destruction of the internal switch contact can occur.

Similar to the mechanical potentiometer, the resistance of the RDAC between the wiper W and terminal A also produces a digitally controlled complementary resistance,  $R_{WA}$ . When these terminals are used, the B terminal can be opened. Setting the resistance value for  $R_{WA}$  starts at a maximum value of resistance and decreases as the data loaded in the latch increases in value. The general equation for this operation is

$$R_{WA}(D) = \frac{256 - D}{128} \times R_{AB} + 2 \times R_W$$
(2)

For  $R_{AB} = 10 \text{ k}\Omega$  and the B terminal open-circuited, the following output resistance  $R_{WA}$  is set for the RDAC latch codes, as shown in Table 6.

Table 6. Codes and Corresponding R<sub>WA</sub> Resistance

D (Dec.)	R <sub>WA</sub> (Ω)	Output State
255	139	Full-Scale
128	5,060	Midscale
1	9,961	1 LSB
0	10,060	Zero-Scale

Typical device-to-device matching is process lot dependent and may vary by up to  $\pm 30\%$ . Because the resistance element is processed using thin film technology, the change in R<sub>AB</sub> with temperature has a very low 35 ppm/°C temperature coefficient.

#### PROGRAMMING THE POTENTIOMETER DIVIDER Voltage Output Operation

The digital potentiometer easily generates a voltage divider at wiper-to-B and wiper-to-A proportional to the input voltage at A-to-B. Unlike the polarity of  $V_{DD}$  to GND, which must be positive, voltage across A-B, W-A, and W-B can be at either polarity.

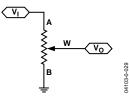


Figure 38. Potentiometer Mode Configuration

If ignoring the effect of the wiper resistance for approximation, connecting the A terminal to 5 V and the B terminal to ground produces an output voltage at the wiper-to-B starting at 0 V up to 1 LSB less than 5 V. Each LSB of voltage is equal to the voltage applied across terminal AB divided by the 256 positions of the potentiometer divider. The general equation defining the output voltage at  $V_W$  with respect to ground for any valid input voltage applied to terminals A and B is

$$V_W(D) = \frac{D}{256} V_A + \frac{256 - D}{256} V_B$$
(3)

For a more accurate calculation, which includes the effect of wiper resistance,  $V_W$  can be found as

$$V_{W}(D) = \frac{R_{WB}(D)}{R_{AB}} V_{A} + \frac{R_{WA}(D)}{R_{AB}} V_{B}$$
(4)

Operation of the digital potentiometer in the divider mode results in a more accurate operation over temperature. Unlike the rheostat mode, the output voltage is dependent mainly on the ratio of the internal resistors  $R_{WA}$  and  $R_{WB}$  and not the absolute values. Thus, the temperature drift reduces to 15 ppm/°C.

#### **ESD PROTECTION**

All digital inputs—SDA, SCL, AD0, and AD1— are protected with a series input resistor and parallel Zener ESD structures, as shown in Figure 39 and Figure 40.

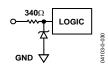


Figure 39. ESD Protection of Digital Pins

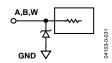


Figure 40. ESD Protection of Resistor Terminals

#### **TERMINAL VOLTAGE OPERATING RANGE**

The AD5172/AD5173  $V_{DD}$  to GND power supply defines the boundary conditions for proper 3-terminal digital potentiometer operation. Supply signals present on terminals A, B, and W that exceed  $V_{DD}$  or GND are clamped by the internal forwardbiased diodes (see Figure 41).

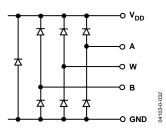


Figure 41. Maximum Terminal Voltages Set by V<sub>DD</sub> and GND

#### **POWER-UP SEQUENCE**

Because the ESD protection diodes limit the voltage compliance at terminals A, B, and W (see Figure 41), it is important to power  $V_{DD}$ /GND before applying any voltage to terminals A, B, and W. Otherwise, the diode will be forward biased such that  $V_{DD}$  is powered unintentionally and may affect the rest of the user's circuit. The ideal power-up sequence is GND,  $V_{DD}$ , the digital inputs, and then  $V_A/V_B/V_W$ . The relative order of powering  $V_A$ ,  $V_B$ ,  $V_W$ , and the digital inputs is not important as long as they are powered after  $V_{DD}$ /GND.

#### POWER SUPPLY CONSIDERATIONS

To minimize the package pin count, both the one-time programming and normal operating voltage supplies are applied to the same V<sub>DD</sub> terminal of the AD5172/AD5173. The AD5172/ AD5173 employ fuse link technology that requires 6 V to blow the internal fuses to achieve a given setting. The user is allowed only one attempt at blowing the fuses. Once programming is completed, power supply voltage must be reduced to the normal 2.7 V to 5.5 V operating range. Such dual voltage requirements require isolation between the supplies. The fuse programming supply (either an on-board regulator or rack-mount power supply) must be rated at 6 V and must be able to provide a 100 mA transient current for 400 ms for successful one-time programming. Once programming is complete, the 6 V supply must be removed to allow normal operation at 2.7 V to 5.5 V at regular microamp current levels. Figure 42 shows the simplest implementation using a jumper. This approach saves one voltage supply, but draws additional current and requires manual configuration.

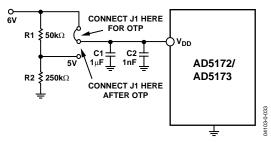


Figure 42. Power Supply Requirement

An alternate approach in 3.5 V to 5.5 V systems adds a signal diode between the system supply and the OTP supply for isolation, as shown in Figure 43.

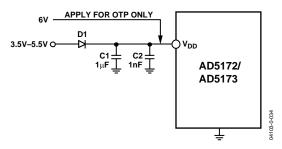


Figure 43. Isolate 6 V OTP Supply from 3.5 V to 5.5 V Normal Operating Supply. The 6 V supply must be removed once OTP is completed.

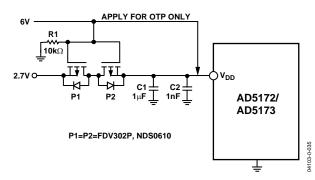


Figure 44. Isolate 6 V OTP Supply from 2.7 V Normal Operating Supply. The 6 V supply must be removed once OTP is completed.

For users who operate their systems at 2.7 V, use of the bidirectional low threshold P-Ch MOSFETs is recommended for the supply's isolation. As shown in Figure 44, this assumes that the 2.7 V system voltage is applied first, and that the P1 and P2 gates are pulled to ground, thus turning on P1 and subsequently P2. As a result, V<sub>DD</sub> of the AD5172/AD5173 approaches 2.7 V. When the AD5172/AD5173 setting is found, the factory tester applies the 6 V to V<sub>DD</sub>; the 6 V is also applied to the gates of P1 and P2 to turn them off. The OTP command is executed at this time to program the AD5172/AD5173; the 2.7 V source is therefore protected. Once the OTP is completed, the tester withdraws the 6 V and the AD5172/AD5173's setting is fixed permanently.

AD5172/AD5173 achieves the OTP function through blowing internal fuses. Users should always apply the 6 V one-time program voltage requirement at the first program command. Failure to comply with this requirement may lead to the change of fuse structures, rendering programming inoperable. Poor PCB layout introduces parasitics that may affect the fuse programming. Therefore, it is recommended to add a 1  $\mu$ F tantalum capacitor in parallel with a 1 nF ceramic capacitor as close as possible to the V<sub>DD</sub> pin. These capacitors help ensure OTP programming success by providing proper current densities. This combination of capacitor values provides both a fast response for high frequency transients and a larger supply of current for extended spikes. Typically, C1 minimizes any transient disturbances and low frequency ripple, while C2 reduces high frequency noise.

#### LAYOUT CONSIDERATIONS

It is a good practice to employ compact, minimum lead length layout design. The leads to the inputs should be as direct as possible with a minimum conductor length. Ground paths should have low resistance and low inductance.

Note that the digital ground should also be joined remotely to the analog ground at one point to minimize the ground bounce.

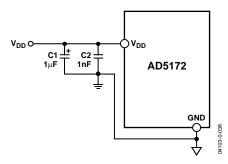


Figure 45. Power Supply Bypassing

## **EVALUATION SOFTWARE/HARDWARE**

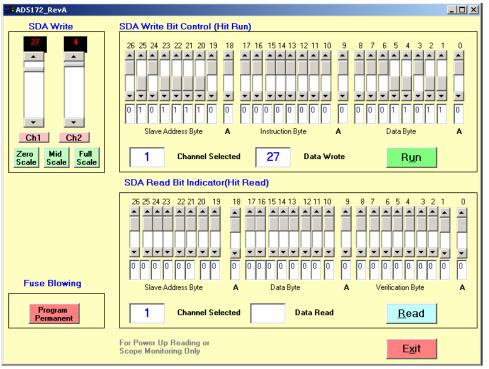


Figure 46. AD5172/AD5173 Computer Software Interface

There are two ways of controlling the AD5172/AD5173. Users can either program the devices with computer software or with external I<sup>2</sup>C controllers.

#### SOFTWARE PROGRAMMING

Due to the advantages of the one-time programmable feature, users may consider programming the device in the factory before shipping the final product to end-users. ADI offers a device programming software that can be implemented in the factory on PCs running Windows 95 or later. As a result, external controllers are not required, which significantly reduces development time. The program is an executable file that does not require any programming languages or user programming skills. It is easy to set up and to use. Figure 46 shows the software interface. The software can be downloaded from www.analog.com. The AD5172/AD5173 starts at midscale after power-up prior to OTP programming. To increment or decrement the resistance, the user may simply move the scrollbars on the left. To write any specific value, the user should use the bit pattern in the upper screen and press the Run button. The format of writing data to the device is shown in Table 7. Once the desired setting is found, the user may press the Program Permament button to blow the internal fuse links.

To read the validation bits and data out from the device, the user simply presses the Read button. The format of the read bits is shown in Table 8.

To apply the device programming software in the factory, users must modify a parallel port cable and configure Pins 2, 3, 15, and 25 for SDA\_write, SCL, SDA\_read, and DGND, respectively, for the control signals (Figure 47). Users should also lay out the PCB of the AD5172/AD5173 with SCL and SDA pads, as shown in Figure 48, such that pogo pins can be inserted for factory programming.

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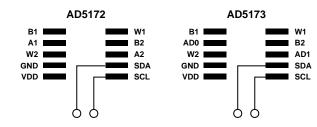


Figure 48. Recommended AD5172/AD5173 PCB Layout. The SCL and SDA pads allow pogo pins to be inserted so that signals can be communicated through the parallel port for programming (Figure 47).

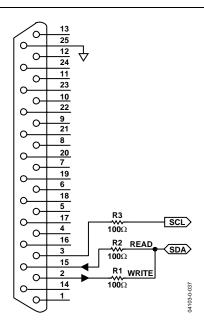


Figure 47. Parallel Port Connection. Pin 2 = SDA\_write, Pin 3 = SCL, Pin 15 = SDA\_read, and Pin 25 = DGND.

#### **I<sup>2</sup>C INTERFACE**

Table 7. Write Mode

#### AD5172

S	0	1	0	1	1	1	1	W	А	A0	SD	Т	0	OW	Х	Х	Х	А	D7	D6	D5	D4	D3	D2	D1	D0	Α	Р
			Slave	e Ado	dress	Byte				Instruction Byte												Data	Byte					

#### AD5173

S	0	1	0	1	1	AD1	AD0	$\overline{W}$	А	A0	SD	Т	0	OW	Х	Х	Х	А	D7	D6	D5	D4	D3	D2	D1	D0	А	Р
			Slav	e Ad	dres	s Byte				Instruction Byte												Data	Byte					

#### Table 8. Read Mode

#### AD5172

S	0	1	0	1	1	1	1	R	А	D7	D6	D5	D4	D3	D2	D1	D0	А	E1	E0	Х	Х	Х	Х	Х	Х	А	Р
			Slav	e Ado	dress	Byte				Instruction Byte												Data	Byte					

AD5173

S	0	1	0	1	1	AD1	AD0	R	А	D7	D6	D5	D4	D3	D2	D1	D0	А	E1	E0	Х	Х	Х	Х	Х	Х	А	Р
			Slave Address Byte Instruction Byte Data Byte																									

S = Start Condition

P = Stop Condition

A = Acknowledge

AD0, AD1 = Package Pin Programmable Address Bits

X = Don't Care

 $\overline{W} = Write$ 

R = Read

A0 = RDAC Subaddress Select Bit

SD = Shutdown connects wiper to B terminal and open circuits the A terminal. It does not change contents of wiper register.

T = OTP Programming Bit. Logic 1 programs the wiper permanently.

OW = Overwrite the fuse setting and program the digital potentiometer to a different setting. Note that upon power-up, the digital potentiometer is preset to either midscale or fuse setting, depending on whether not the fuse link has been blown.

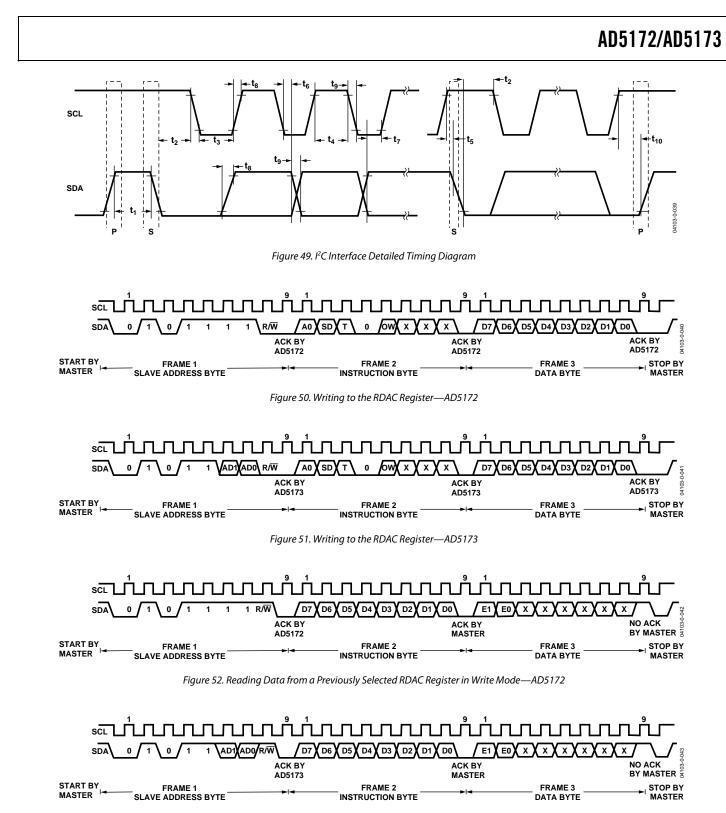
D7, D6, D5, D4, D3, D2, D1, D0 = Data Bits.

E1, E0 = OTP Validation Bits.

0, 0 =Ready to Program.

1, 0 = Fatal Error. Some fuses not blown. Do not retry. Discard this unit.

1, 1 = Programmed Successfully. No further adjustments possible.





#### I<sup>2</sup>C COMPATIBLE 2-WIRE SERIAL BUS

The 2-wire I<sup>2</sup>C serial bus protocol operates as follows:

1. The master initiates data transfer by establishing a START condition, which is when a high-to-low transition on the SDA line occurs while SCL is high (see Figure 50 and Figure 51). The following byte is the slave address byte, which consists of the slave address followed by an  $R/\overline{W}$  bit (this bit determines whether data is read from or written to the slave device). The AD5172 has a fixed slave address byte, whereas the AD5173 has two configurable address bits, AD0 and AD1 (see Figure 50 and Figure 51).

The slave whose address corresponds to the transmitted address responds by pulling the SDA line low during the ninth clock pulse (this is termed the acknowledge bit). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to or read from its serial register. If the  $R/\overline{W}$  bit is high, the master reads from the slave device. If the  $R/\overline{W}$  bit is low, the master writes to the slave device.

2. In the write mode, the second byte is the instruction byte. The first bit (MSB) of the instruction byte is the RDAC subaddress select bit. A logic low selects channel 1; a logic high selects channel 2.

The second MSB, SD, is a shutdown bit. A logic high causes an open circuit at terminal A while shorting the wiper to terminal B. This operation yields almost 0  $\Omega$  in rheostat mode or 0 V in potentiometer mode. It is important to note that the shutdown operation does not disturb the contents of the register. When brought out of shutdown, the previous setting is applied to the RDAC. Also, during shutdown, new settings can be programmed. When the part is returned from shutdown, the corresponding VR setting is applied to the RDAC.

The third MSB, T, is the OTP programming bit. A logic high blows the poly fuses and programs the resistor setting permanently.

The fourth MSB must always be at Logic 0.

The fifth MSB, OW, is an overwrite bit. When raised to a logic high, OW allows the RDAC setting to be changed even after the internal fuses have been blown. However, once OW is returned to a logic zero, the position of the RDAC returns to the setting prior to overwrite. Because OW is not static, if the device is powered off and on, the RDAC presets to midscale or to the setting at which the fuses were blown, depending on whether or not the fuses have been permanently set already.

The remainder of the bits in the instruction byte are don't cares (see Figure 50 and Figure 51).

After acknowledging the instruction byte, the last byte in write mode is the data byte. Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit). The transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL (see Figure 49).

3. In the read mode, the data byte follows immediately after the acknowledgment of the slave address byte. Data is transmitted over the serial bus in sequences of nine clock pulses (a slight difference from the write mode, where there are eight data bits followed by an acknowledge bit). Similarly, the transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL (see Figure 52 and Figure 53).

Note that the channel of interest is the one that is previously selected in the write mode. In the case where users need to read the RDAC values of both channels, they must program the first channel in the write mode and then change to the read mode to read the first channel value. After that, the user must change back to the write mode with the second channel selected and read the second channel value in the read mode. It is not necessary for users to issue the Frame 3 data byte in the write mode for subsequent readback operation. Refer to Figure 52 and Figure 53 for the programming format.

Following the data byte, the validation byte contains two validation bits, E0 and E1. These bits signify the status of the one-time programming (see Figure 52 and Figure 53).

4. After all data bits have been read or written, a STOP condition is established by the master. A STOP condition is defined as a low-to-high transition on the SDA line while SCL is high. In write mode, the master pulls the SDA line high during the 10<sup>th</sup> clock pulse to establish a STOP condition (see Figure 50 and Figure 51). In read mode, the master issues a No Acknowledge for the ninth clock pulse (i.e., the SDA line remains high). The master then brings the SDA line low before the 10<sup>th</sup> clock pulse, which goes high to establish a STOP condition (see Figure 52 and Figure 53).

A repeated write function gives the user flexibility to update the RDAC output a number of times after addressing and instructing the part only once. For example, after the RDAC has acknowledged its slave address and instruction bytes in the write mode, the RDAC output is updated on each successive byte. If different instructions are needed, the write/read mode has to start again with a new slave address, instruction, and data byte. Similarly, a repeated read function of the RDAC is also allowed.

#### Table 9. Validation Status

E1	E0	Status
0	0	Ready for Programming.
1	0	Fatal Error. Some fuses not blown. Do not retry. Discard this unit.
1	1	Successful. No further programming is possible.

#### Multiple Devices on One Bus(AD5173 Only)

Figure 54 shows four AD5173s on the same serial bus. Each has a different slave address because the states of their AD0 and AD1 pins are different. This allows each device on the bus to be written to or read from independently. The master device output bus line drivers are open-drain pull-downs in a fully I<sup>2</sup>C compatible interface.

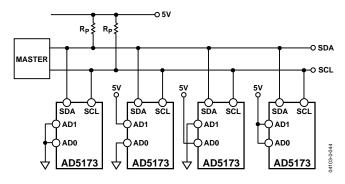


Figure 54. Multiple AD5173s on One I<sup>2</sup>C Bus

## **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**

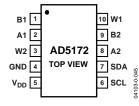


Figure 55. AD5172 Pin Configuration

Table 10.	AD5172 P	in Function	Descriptions
Table IV.	<b>MD31/41</b>	in i unction	Descriptions

1401							
Pin	Menmonic	Description					
1	B1	B1 Terminal.					
2	A1	A1 Terminal.					
3	W2	W2 Terminal.					
4	GND	Digital Ground.					
5	V <sub>DD</sub>	Positive Power Supply.					
6	SCL	Serial Clock Input. Positive edge triggered.					
7	SDA	Serial Data Input/Output.					
8	A2	A2 Terminal.					
9	B2	B2 Terminal.					
10	W1	W1 Terminal.					

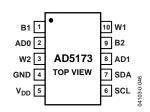


Figure 56. AD5173 Pin Configuration

Pin	Mnemonic	Description
1	B1	B1 Terminal.
2	AD0	Programmable Address Bit 0 for Multiple Package Decoding.
3	W2	W2 Terminal.
4	GND	Digital Ground.
5	V <sub>DD</sub>	Positive Power Supply.
6	SCL	Serial Clock Input. Positive edge triggered.
7	SDA	Serial Data Input/Output.
8	AD1	Programmable Address Bit 1 for Multiple Package Decoding.
9	B2	B2 Terminal.
10	W1	W1 Terminal.

## **OUTLINE DIMENSIONS**

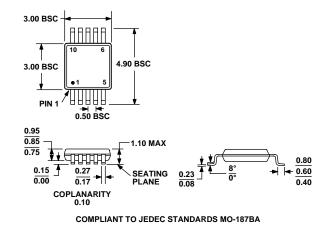


Figure 57. 10-Lead Mini Small Outline Package [MSOP] (RM-10) Dimensions shown in millimeters

#### **ORDERING GUIDE**

Model	R <sub>AB</sub> (kΩ)	Temperature Range	Package Description	Package Option	Branding	
AD5172BRM2.5	2.5	-40°C to +125°C	MSOP-10	RM-10	D0U	
AD5172BRM2.5-RL7	2.5	-40°C to +125°C	MSOP-10	RM-10	D0U	
AD5172BRM10	10	-40°C to +125°C	MSOP-10	RM-10	D0V	
AD5172BRM10-RL7	10	-40°C to +125°C	MSOP-10	RM-10	D0V	
AD5172BRM50	50	-40°C to +125°C	MSOP-10	RM-10	D10	
AD5172BRM50-RL7	50	-40°C to +125°C	MSOP-10	RM-10	D10	
AD5172BRM100	100	-40°C to +125°C	MSOP-10	RM-10	D11	
AD5172BRM100-RL7	100	-40°C to +125°C	MSOP-10	RM-10	D11	
AD5172EVAL <sup>1</sup>			Evaluation Board			
AD5173BRM2.5	2.5	-40°C to +125°C	MSOP-10	RM-10	D1K	
AD5173BRM2.5-RL7	2.5	-40°C to +125°C	MSOP-10	RM-10	D1K	
AD5173BRM10	10	-40°C to +125°C	MSOP-10	RM-10	D1L	
AD5173BRM10-RL7	10	-40°C to +125°C	MSOP-10	RM-10	D1L	
AD5173BRM50	50	-40°C to +125°C	MSOP-10	RM-10	D1M	
AD5173BRM50-RL7	50	-40°C to +125°C	MSOP-10	RM-10	D1M	
AD5173BRM100	100	-40°C to +125°C	MSOP-10	RM-10	D1N	
AD5173BRM100-RL7	100	-40°C to +125°C	MSOP-10	RM-10	D1N	
AD5173EVAL <sup>1</sup>			Evaluation Board			

 $^{1}$  The evaluation board is shipped with the 10 k $\Omega$  R<sub>AB</sub> resistor option; however, the board is compatible with all available resistor value options.

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